Data Sheet

BIT3106A

High Efficiency Dual PWM Controller

Version: 1.2

Notice

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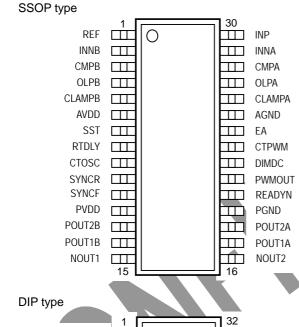
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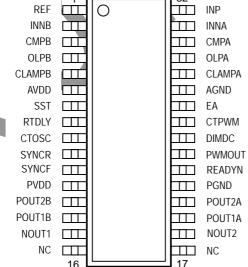
BIT3106A

Features:

- 4.5V ~ 13.2V Operation Voltage
- Support Dual Full Bridge, Push-Pull or Class-E Fixed Frequency PWM Control
- High Accuracy Multi-Lamp Synchronous Operation
- Built-in PWM Dimming
- Programmable Soft Start
- Programmable Striking Voltage
- Dual Independent Latched Open Lamp Protection
- ON/OFF Control with almost zero Standby Current
- Rail-to-Rail Totem Pole Output
- Low Power CMOS Process

Pin Layout:





Recommended Operating Condition:

Supply Voltage	4.5 ~ 13.2 V
Operating Ambient Temperature	0 ~ 70
Operating Frequency	30K ~ 250K Hz

Applications:

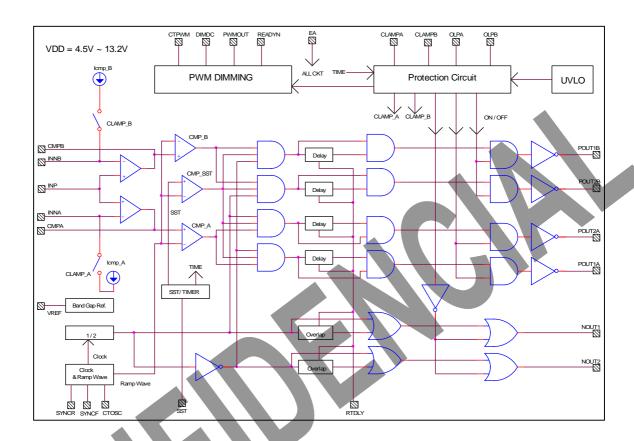
- Cold Cathode Fluorescent Lamps system
- External Electrode Fluorescent Lamps system
- LCD Monitor
- LCD PC
- LCD TV
- Video Phone/ Door Phone
- Navigation Devices (GPS Equipment)
- ATM/ Financial Terminal
- POS Terminal

General Description:

BIT3106A integrated dual fixed frequency controller and the essential features for controlling the CCFL/EEFL. New developed PWM configuration provides a general solution to support Full-bridge (4-Switches), Push-Pull (2-Switches) or Class-E (1-Switch) control circuitry to regulate the current of the lamps. The synchronization design synchronizes both of frequency and phase of the lamps. Such design makes BIT3106A especially suitable for high brightness, multi-lamp LCD backlight applications. BIT3106A senses the lamp current directly to enable the built-in PWM dimming. If no current flow into the lamp, BIT3106A provides a continuous AC output to ensure the successful ignition, PWM dimming is started immediately while both of the lamps are ignited. For more than two lamps applications, BIT3106A senses all of the lamps that are driven by different ICs and start the PWM dimming while all of the lamps are ignited. BIT3106A uses up to 13.2V high voltage CMOS process to design the output drivers to drive high side PMOS switches directly without any boost circuitry. BIT3106A provides dual clamped striking voltage control loops to protect transformer while ignition and the lamp current monitors provide the independent reliable latched open lamp protection.

Patent number 90215947

Functional Block Diagram:



Functional Description:

UVLO: The under-voltage-lookout circuit turns the output driver off when supply voltage drops too low. System is shut down with all outputs turned to logic high level.

Band Gap Reference: An internal trimmed band-gap reference provides a high accuracy and temperature insensitive voltage reference. By amplifying or dividing this voltage that can generate the other required reference voltages.

Over Voltage Clamping: While a > 2.0V is sensed by CLAMPA/B pin, an internal ~ 180uA current will flow into the pin INNA (INNB), the inverting input of the error amplifier, to clamp the output.

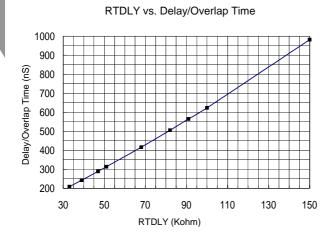
On/Off Function: The EA pin provides the function to turn on and off the output without shut down the supply voltage. An internal 80K ohm pulled low resistor is connected here. All of the outputs are forced to logic high will the chip is turned off.

Set the Delay/Overlap Time for ZVS Operation: The period of the internal delay generation circuitry dependent on the resistance of R_{RTDLY}. The CCFL control requires timing circuitry, the required period of ignition, lamp operation frequency, PWM dimming PWM frequency and the delay/overlap for ZVS switching. The resistor R_{RTDLY} connected to pin RTDLY and the internal 1.25V determines a reference current I_{REF} with

The Delay/Overlap time T_{Delay} and T_{Overlap} in typical

$$I_{REF} = \frac{1.25V}{R_{REF}}$$
...(1)

case; 12V, 25°C operation, can be found from bellow:



Set the Lamp Operation Frequency: The lamp operation frequency can be calculated as equation (2)

$$F_{LAMP} = \frac{1.3}{R_{RTDLY} \times C_{CTOSC}}....(2)$$

For a 45KHz operation if an 82K ohm resistor is used as the delay resistor. A 350pF capacitor can be connected to the pin CTOSC.

The Soft Start and Open Lamp Protection: A current mirror provides current with value $\sim 0.02 \text{ x I}_{REF}$ to charge the SST pin. The slope of Soft Start $\Delta V/\Delta T$ can be determined by

$$\frac{\Delta V}{\Delta T} = \frac{0.025}{R_{RTDLY} \times C_{SST}} \dots (3$$

The required time of ignition is set as equation (4)

$$T_{\text{STRIKE}} = 50 \times R_{\text{RTDLY}} \times C_{\text{SST}}.....(4)$$

In the case of $R_{RTDLY}=82K$ ohm. A 0.47 uF capacitor connected on the pin SST can set a ~ 2 S period for striking the lamp. If the voltage of OLPA/B pin less than 600mV or a >2.0V signal is sensed by CLAMPA/B pin, after striking period, the latched protection function will latch the output drivers to VDD high level. The latched situation can be released while the system is re-started.

PWM Dimming: To compare the input of pin DIMDC and the 0.5V ~ 2.0V ramp wave makes the PWM pulses for PWM dimming. The internal ramp wave generator generates a ramp wave with peak=2V and valey=0.5V. Its frequency can be set as equation (5)

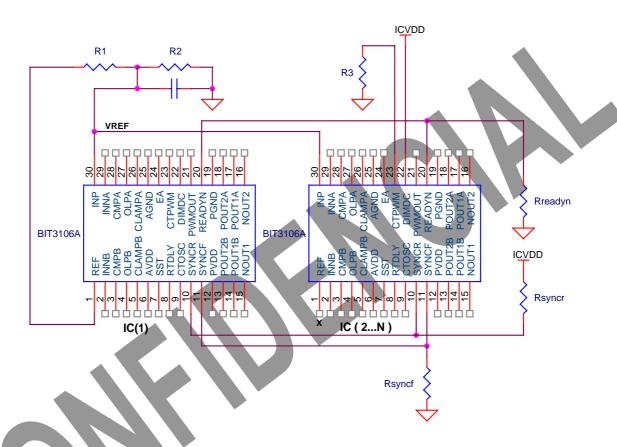
$$F_{PWM} = \frac{0.42}{R_{RTDLY} \times C_{CTPWM}} \dots (5)$$

The output of pin PWMOUT is pulled to VDD to make the dark portion of the CCFL output bursts and the floating state to make the bright portion. A less than 0.5V input on pin DIMDC will make the PWMOUT to be floating to obtain 100% brightness. BIT3106A provides the continuous high voltage to strike the lamp. It sends the PWM pulse while the voltage of READYN pin is a logic low level.

Multi-Lamp Operation: In the case of multi-lamp operation, several criteria must be considered:

- (1)To keep the lamp current to be balanced.
- (2)To synchronize the lamp frequency to reduce the interference.
- (3)To synchronize the phase of the lamps to minimize the leakage between the lamps.
- (4)To determine when to start the PWM dimming.

The bellowing figure is an example to use more than one BIT3106A for multi-lamp operation.



In above figure each chip uses same reference that can keep the lamps balanced. BIT3106A uses two-pin SYNCR (10) and SYNCF (11) to synchronize both of lamp frequency and phase. With two ~ 51 K ohm resistors connected to VDD and GND as above figure shows, the chip with highest frequency will dominate the operation frequency and phase of the whole system. The timing of PWM dimming is dependent on operation situations. In normal case, all of the lamps have been ignited then the pin READYN is pulled to logic low level to start the bursts from pin PWMOUT. But if any one of the lamps is open, the burst will be sent while the user set striking period has been over.

Pin Description:

Pin	Names	I/O	Description				
1	REF	0	Trimmed band gap reference voltage output.				
2	INNB	I	The inverting input of the error amplifier of the channel B.				
3	CMPB	I/O	The output of the error amplifier of the channel B.				
4	OLPB	I	Lamp current detection pin of channel B, the open lamp situation is detected if a less than 600mV input is sensed.				
5	CLAMPB	I/O	Over voltage clamping of channel B. If a > 2 V voltage is detected. A ~ 180uA current will flow into the INNB pin to reduce the output of the error amplifier CMPB to clamp the output voltage.				
6	AVDD	ı	The power supply of analog control circuitry.				
7	SST	0	With the RTDLY pin made reference current and an external capacitor connected here can set the required period of ignition and the slop of soft start. The open lamp protection function will be enabled after this node is charged to > 2.5V.				
8	RTDLY	I/O	An external resistor connected here makes a reference current which determines the delay and overlap timing of the output drivers. With this reference current and different capacitors can set the period of soft start, the frequency of PWM dimming and the operation frequency of the lamp.				
9	CTOSC	I/O	With the RTDLY pin made reference current and an external capacitor connected here can set the lamp operation frequency.				
10	SYNCR	I/O	SYNCR and SYNCF pins are used as the frequency and phase synchronization. It requires an ~51Kohm resistor connected here to AVDD to implement the synchronization.				
11	SYNCF	0	SYNCR and SYNCF pins are used as the frequency and phase synchronization. It requires an ~51Kohm resistor connected here to AGND to implement the synchronization.				
12	PVDD	ı	The power supplies input output drivers.				
13	POUT2B	0	The number 2 PMOSFET switch driver of channel B.				
14	POUT1B	0	The number 1 PMOSFET switch driver of channel B.				
15	NOUT1	0	The number 1 NMOSFET switch driver of channel A, B.				
16	NOUT2	0	The number 2 NMOSFET switch driver of channel A, B.				
17	POUT1A	0	The number 1 PMOSFET switch driver of channel A.				
18	POUT2A	0	The number 2 PMOSFET switch driver of channel A.				
19	PGND	I/O	The ground pin of the output drivers.				
20	READYN	I	The ignition indicator of the system. An external ~ 51K ohm pulled low resistor must be used here. A logic low output will enable the output of PWM dimming.				
21	PWMOUT	9	The output of PWM dimming. An ~ 200ohm pull to AVDD switch can be used to turn off the lamp with low frequency.				
22	DIMDC	1	PWM dimming control input. A PWM output comes out by comparing this DC input and the triangle wave that is generated by CTPWM.				
23	СТРШМ	1/0	With the RTDLY pin made reference current and an external capacitor connected here can set the PWM dimming operation frequency and a 0.5V ~ 2V triangle wave output is generated for PWM input				
24	EA		ON/OFF control pin, 1.2V threshold with an internal 80K \pm 15% ohm pull low resistor.				
25	AGND	NO	The ground pin of the analog control circuitry.				
26	CLAMPA	1/0	Over voltage clamping of channel A. If a > 2 V voltage is detected. A ~ 180uA current will flow into the INNA pin to reduce the output of the error amplifier CMPA to clamp the output voltage.				
27	OLPA	ı	Lamp current detection pin of channel A, the open lamp situation is detected if a less than 600mV input is sensed.				
28	CMPA	I/O	The output of the error amplifier of the channel A.				
29	INNA	I	The inverting input of the error amplifier of the channel A.				
30	INP	I	The Non-inverting input of the error amplifier of both channel A, B.				

Absolute Ratings: (if Ta=25)

Parameter	Symbol	Ratings	Unit	Remarks
Control Supply Voltage	AVDD	-0.3~+ 13.7	V	Ta=25°C
Analog Ground	AGND	±0.3	V	
Driver Supply Voltage	PVDD	-0.3~+ 13.7	V	
Driver Ground	PGND	±0.3	V	
Input Voltage		-0.3~ VDD+0.3	V	
Operating Ambient Temperature	Ta	0~ +70	°C	
Operating Junction Temperature		+150	°C	
Storage Temperature		-55~+150	°C	

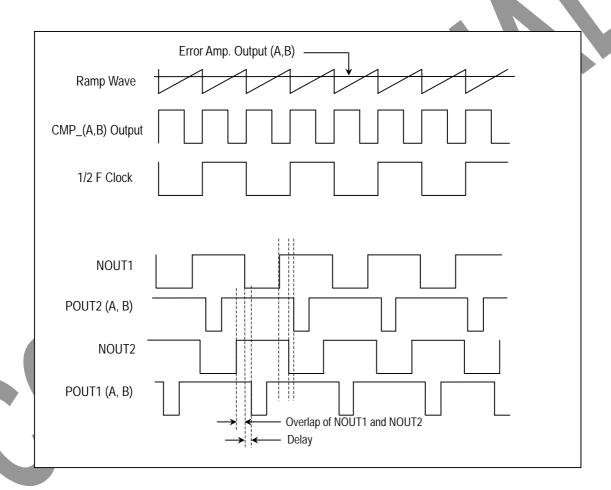
DC/AC Characteristics:

Supply Voltages	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
AVDD(Note1)		100t Contamono		1,76.	maxi	0
PVDD(Note1) 12V AVDD, 12V PVDD 3			15		13.2	\/
Chip Consumed Current	,					
Ta=25°C 3	1 VDD(Note1)	12\/ A\/DD	4.5		13.2	V
Reference Voltage	Chip Consumed Current	· ·		3		mA
12V, Ta=25°C	Reference Voltage	14-25 0		1		
Line regulation)	12V. Ta=25°C		2.5		V
Under Voltage Look Out					20	mV
Positive Going Threshold						
Hysteresis 0.1		Ta=25°C	3.8	4	4.2	V
Ramp Wave Generator and Lamp Frequency Operating Frequency Output peak 2.25 V Output valley 0.45 V Output valley Output valley 0.45 V Output valley						1/
Note 2 30 250 KHz			0.1	0.2	0.3	V
Output valley Output valley Cerror Amplifier Open loop gain Unit gain band width SST Soft Start and Open Lamp Enable Output current Open Lamp Detection Enable Output current Open Lamp Detection Enable OUtput B pin Open lamp detection lower threshold CMP pin Open lamp detection lower threshold CMP pin Open lamp detection lower threshold CMP pin Open lamp detection lower threshold CLAMPA/B pin detection lower threshold INN pin driving current ONOrt Voltage Clamping CLAMPA/B pin detection lower threshold INN pin driving current ONOR DIAMPA/B pin detection lower threshold INN pin driving current ONOR DIAMPA/B pin detection lower threshold INN pin driving current ONOR DIAMPA/B pin detection lower threshold INN pin driving current ONOR DIAMPA/B pin detection lower threshold pin lamp detection lower lamp detection lamp det			00		050	1211
Output valley		INOTEZ	30	0.05	250	
Comparison						
Open loop gain				0.45		V
Unit gain band width SST Soft Start and Open Lamp Enable Output current Open Lamp Detection Enable Open Lamp Protection OLPA/B pin Open lamp detection lower threshold CMP pin Open lamp detection lower threshold CLAMPA/B pin detection lower threshold of EA pin label low resistance Fine threshold of EA pin label low resistance FWM Dimming Ramp Wave Peak Ramp Wave Peak Ramp Wave Peak Ramp Wave Valley PWM Frequency 100 % Brightness Dimming Voltage on pin DIMDC 0 % Brightn	•		00	V 60 =		15
SST Soft Start and Open Lamp Enable					1 7	
Output current Open Lamp Detection Enable Open Lamp Detection Enable Open Lamp Protection OLPA/B pin Open lamp detection lower threshold CMP pin Open lamp detection lower lamp detection			1	1.5		MHz
Open Lamp Detection Enable Open Lamp Protection OLPA/B pin Open lamp detection lower threshold CMP pin Open lamp detection lower threshold Hysterisis CLAMPA/B pin detection lower threshold CLAMPA/B pin detection lower threshold Hysterisis CLAMPA/B pin detecti						1 .
Open Lamp Protection OLPA/B pin Open lamp detection lower threshold CMP pin Open lamp detection lower threshold CMP pin Open lamp detection lower threshold Hysterisis 20 mV Over Voltage Clamping CLAMPA/B pin detection lower threshold Hysterisis 20 mV Over Voltage Clamping CLAMPA/B pin detection lower threshold Hysterisis 20 mV INN pin driving current 180 uA On/Off Function The threshold of EA pin The threshold of EA pin Internal pulled low resistance PWM Dimming Ramp Wave Peak Ramp Wave Peak Ramp Wave Valley PWM Frequency 100 % Brightness Dimming Voltage on pin DIMDC Ow & Brightness Dimming Voltage on pin DIMDC Pulled high resistance of Pin PWMOUT output for making the bright burst Output CMOS output impedance (Note2, Note3) VDD=5V, 1000pF(Note3, 110 Rough Service Script		VDD=12V, Ta=25°C				
OLPA/B pin Open lamp detection lower threshold CMP pin Open lamp detection lower threshold CMP pin Open lamp detection lower threshold Hysterisis CLAMPA/B pin detection lower threshold CLAMPA/B pin detection lower threshold CLAMPA/B pin detection lower threshold Hysterisis CLAMPA/B pin detection lower threshold Hysterisis 20 mV WDD=12V, Ta=25°C 2.0 V Hysterisis 20 mV INN pin driving current 0180 uA Orv/Off Function The threshold of EA pin Internal pulled low resistance PWM Dimming Ramp Wave Peak Ramp Wave Peak Ramp Wave Valley PWM Frequency 10 % Brightness Dimming Voltage on pin DIMDC 0 % Brightness Dimming Voltage on pin DIMDC Pulled high resistance of Pin PWMOUT output for making the bright burst Output CMOS output impedance (Note2, Note3) VDD=5V, 1000pF(Note3, 110) Important pulled important properties of pin				2.5		V
threshold CMP pin Open lamp detection lower threshold				1		1
CMP pin Open lamp detection lower threshold		VDD=12V, Ta=25°C		600		m\/
CLAMPA/B pin detection lower threshold				000		111.4
Chreshold				2.5		V
Over Voltage Clamping	threshold					•
CLAMPA/B pin detection lower threshold VDD=12V, Ta=25°C 2.0	Hysterisis			20		mV
Streshold Companies Comp	Over Voltage Clamping					
Hysterisis 20	CLAMPA/B pin detection lower	VDD=12V, Ta=25°C		2.0		V
INN pin driving current On/Off Function The threshold of EA pin Internal pulled low resistance PWM Dimming Ramp Wave Peak Ramp Wave Valley PWM Frequency 100 % Brightness Dimming Voltage on pin DIMDC 0 % Brightness Dimming Voltage on pin DIMDC Pulled high resistance of Pin PWMOUT output for making the dark burst Pin PWMOUT output for making the bright burst Output CMOS output impedance Rising Time VDD=12V, Ta=25°C 1.2 V V DD=12V, Ta=25°C 2.0 V 0.5 V 0.5 V 0.5 V 0.5 V 10 10 100K Hz 10 0.5 V 10 100K Hz 100 100K Hz 100K Hz 100 100K Hz 100K Hz 100 100K Hz				2.0		•
Con/Off Function				20		mV
The threshold of EA pin				180		uA
Internal pulled low resistance PWM Dimming Ramp Wave Peak Ramp Wave Valley PWM Frequency 10 100K Hz 100 % Brightness Dimming Voltage on pin DIMDC 0 % Brightness Dimming Voltage on pin DIMDC Pulled high resistance of Pin PWMOUT output for making the bright burst Output CMOS output impedance Rising Time VDD=12V, Ta=25°C 2.0 V 0.5 V 0.5 V 10 100K Hz 10 0.5 V 10 100K Hz 10 0.5 V Floating VDD=12V, Ta=25°C 2.0 V 10 100K Hz 10 100K Hz 10 0.5 V						
Ramp Wave Peak Ramp Wave Valley PWM Frequency 10 100K Hz 100 % Brightness Dimming Voltage on pin DIMDC 0 % Brightness Dimming Voltage on pin DIMDC Pulled high resistance of Pin PWMOUT output for making the dark burst Pin PWMOUT output for making the bright burst Output CMOS output impedance Rising Time VDD=12V, Ta=25°C 2.0 V 10 100K Hz 2 0.5 V 2 V Floating Floating VDD=5V, 1000pF(Note3, 110 ns	The threshold of EA pin	VDD=12V, Ta=25°C		1.2		V
Ramp Wave Peak Ramp Wave Valley PWM Frequency 100 % Brightness Dimming Voltage on pin DIMDC 0 % Brightness Dimming Voltage on pin DIMDC 0 % Brightness Dimming Voltage on pin DIMDC Pulled high resistance of Pin PWMOUT output for making the bright burst Pin PWMOUT output for making the bright burst Output CMOS output impedance Rising Time VDD=12V, Ta=25°C 2.0 V 10 100K Hz	Internal pulled low resistance			80K		
Ramp Wave Valley PWM Frequency 100 % Brightness Dimming Voltage on pin DIMDC 0 % Brightness Dimming Voltage on pin DIMDC Pulled high resistance of Pin PWMOUT output for making the bright burst Output CMOS output impedance Ramp Wave Valley 0.5 V 10 100K Hz 2 V 0.5 V 2 V Floating Floating Floating Note2, Note3) Rising Time VDD=5V, 1000pF(Note3, 110 ns	PWM Dimming		-		-	
PWM Frequency 100 % Brightness Dimming Voltage on pin DIMDC 0 % Brightness Dimming Voltage on pin DIMDC Pulled high resistance of Pin PWMOUT output for making the dark burst Pin PWMOUT output for making the bright burst Output CMOS output impedance (Note2, Note3) Rising Time 10	Ramp Wave Peak	VDD=12V, Ta=25°C		2.0		V
100 % Brightness Dimming Voltage on pin DIMDC 0 % Brightness Dimming Voltage on pin DIMDC Pulled high resistance of Pin PWMOUT output for making the dark burst Pin PWMOUT output for making the bright burst Output CMOS output impedance (Note2, Note3) Rising Time 0.5 V 2 V Dividing 10.5 V End 2 V Dividing 10.5 Dividing	Ramp Wave Valley			0.5		V
pin DIMDC 0 % Brightness Dimming Voltage on pin DIMDC Pulled high resistance of Pin PWMOUT output for making the dark burst Pin PWMOUT output for making the bright burst Output CMOS output impedance (Note2, Note3) 50 Rising Time VDD=5V, 1000pF(Note3, 110 ns	PWM Frequency		10		100K	Hz
pin DIMDC 0 % Brightness Dimming Voltage on pin DIMDC Pulled high resistance of Pin PWMOUT output for making the dark burst Pin PWMOUT output for making the bright burst Output CMOS output impedance (Note2, Note3) 50 Rising Time VDD=5V, 1000pF(Note3, 110 ns	100 % Brightness Dimming Voltage on				0.5	\/
DIMDC Pulled high resistance of Pin PWMOUT output for making the dark burst Pin PWMOUT output for making the bright burst Output CMOS output impedance (Note2, Note3) 50 Rising Time VDD=5V, 1000pF(Note3, 110 ns	pin DIMDC				0.5	V
Pulled high resistance of Pin PWMOUT output for making the dark burst Pin PWMOUT output for making the bright burst Output CMOS output impedance (Note2, Note3) 50 Rising Time VDD=5V, 1000pF(Note3, 110 ns	0 % Brightness Dimming Voltage on pin		2			V
Output for making the dark burst 200 Pin PWMOUT output for making the bright burst Floating Output CMOS output impedance (Note2, Note3) 50 Rising Time VDD=5V, 1000pF(Note3, 110 ns	DIMDC					
Pin PWMOUT output for making the bright burst Output CMOS output impedance (Note2, Note3) 50 Rising Time VDD=5V, 1000pF(Note3, 110 ns	Pulled high resistance of Pin PWMOUT			200		
bright burst Floating Output CMOS output impedance (Note2, Note3) 50 Rising Time VDD=5V, 1000pF(Note3, 110 ns	output for making the dark burst			200		
Output (Note2, Note3) 50 Rising Time VDD=5V, 1000pF(Note3, 110 ns	Pin PWMOUT output for making the			Floating		
CMOS output impedance (Note2, Note3) 50 Rising Time VDD=5V, 1000pF(Note3, 110 ns	bright burst			rioaurig		
Rising Time VDD=5V, 1000pF(Note3, 110 ns	Output					
	CMOS output impedance	(Note2, Note3)	-	50	-	
	Rising Time			110		ns
	Falling Time	Note4)		100		ns

- Note 1. AVDD and PVDD must be set to an equal supply voltage VDD in typical application.
- Note 2. The lamp operation frequency is the half of the ramp wave frequency
- Note 3. Only verified by simulation. Not 100% tested.
- Note 4. The voltages of the output drivers are equal to PVDD in each off states.

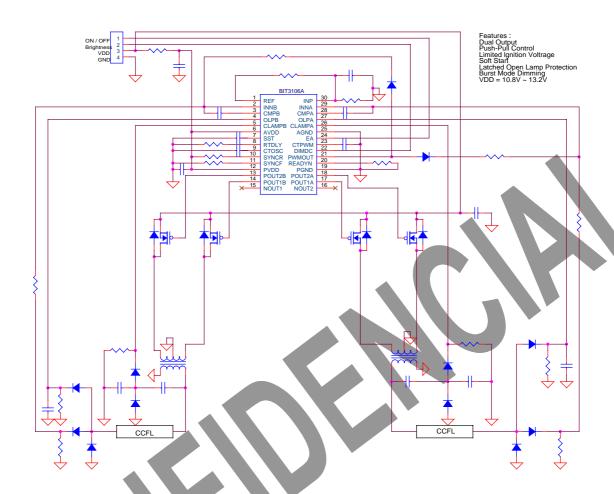
Timing Diagram

BIT3106A uses new developed fixed frequency PWM driving methodology to drive CCFL (or EEFL). The low side switches; NMOSFETs are driven by fixed frequency and fixed; > 50% duty cycle clock signals. The high side switches; PMOSFETs are driven by fixed frequency feedback controlled PWM signals. The detail timing relationship is shown as bellow:

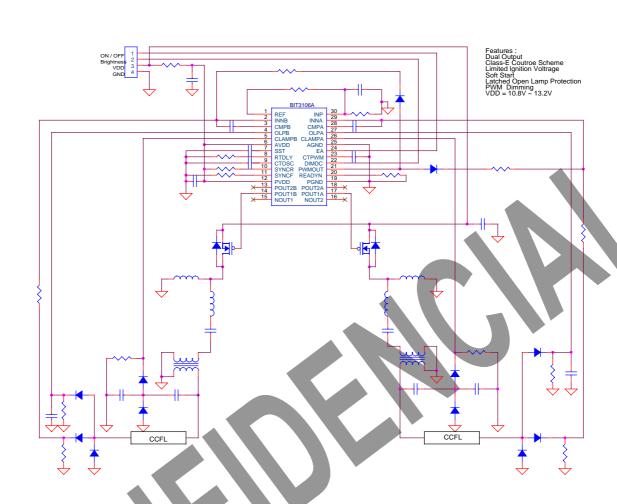


If the lamp operation frequency is set to higher than resonant frequency of the LC tank, symmetry ZVS switching operation can be performed. A well-controlled delay and overlap timing relationship play the key role of this control scheme. It can be set through using proper resistor connected on RTDLY pin. (Patent pending)

Application Information:

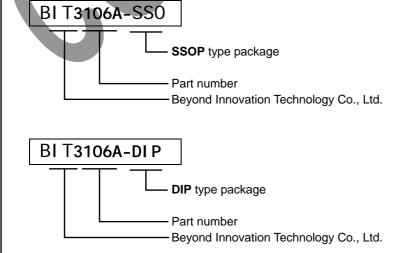


One of the typical applications with push-pull control scheme of BIT3106A



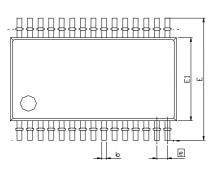
One of the typical applications with Class-E control scheme of BIT3106A

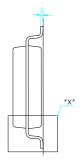
Order Information:



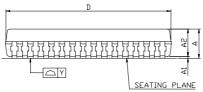
Package Information:

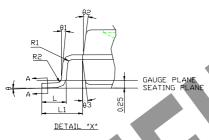
SSOP type:

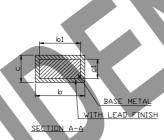




SYMBOL	DIMENSION (MM)			DIMENSION (MIL)		
STRIBLL	MIN.	N□M.	MAX.	MIN.	N□M.	MAX.
Α			2.0			79
A1	0.05	0.13	0.21	2	5	8
A2	1.65	1.75	1.85	65	69	73
lo	0.22		0.38	9		15
lo1	0.22	0.30	0.33	9	12	13
С	0.09		0.25	4		10
⊂1	0.09	0.15	0.21	4	6	8
D	9.90	10.20	10.50	390	402	413
E	7.40	7.80	8.20	291	307	353
E1	5.00	5.30	5.60	197	209	220
е		0.65 BS	С		26 B2C	
L	0.55	0.75	0.95	55	30	37
L1		1.25 REF		49 REF		
R1	0.15	0.20	0.25	6	8	10
R2	0.15	0.20	0.25	6	8	10
Y			0.075		_	3
θ	0*	4*	8.	0.	4*	8*
01	0*			0*		
92	· ·	7° TYP		7° TYP		
03		7° TYP			7° TYP	







DIE:

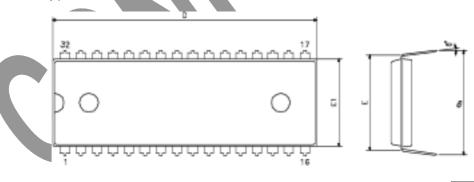
REFER TO JEDEC MO-150AH

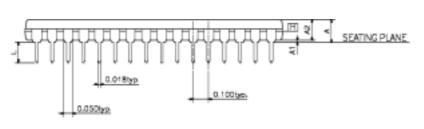
DIMENSION "D" DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS
OR GATE BURRS. MOLD FLASH, PROTRUSIONS AND GATE BURRS
SHALL NOT EXECED 0.15mm (6mi) PER SIDE.

DIMENSION "E" DOES NOT INCLUDE INTERLEAD FLASH OR
PROTRUSIONS. INTER-LEAD FLASH AND PROTRUSI SHALL
NOT EXCEED 0.25mm (10 mil) PER SIDE.

CONTROLLING DIMENSION: MILLIMETER

DIP type





SYMBOLS	MIN.	NOR.	MAX.	
A	_	-	0.220	
A1	0.015	-	-	
A2	0.150	0.155	0.160	
D	1.645	1.650	1.560	
E	0.600 BSC			
E1	0.540	0.545	0.550 0.150	
L	0.115	0.130	0.150	
6 ₈	0.630	0.650	0.670	
e"	0	7	15	
		1.17	VIT - INCH	

NOTE:

1.JEDEC OUTLINE : MS-011 AC